

江苏浩都频率科技有限公司

JIANGSU HD-CRYSTAL TECHNOLOGY CO., LTD

Specifications For Product

TYPE: Quartz Crystal Oscillator

SPEC: QMEMS5032/148.500M/3.3V/±30PPM

P/N : 8Q148500301

VER : A/1

| R&D APPR.SIGNATURED | | | DEPT. |
|---------------------|-------|----------|---|
| ISSUE | CHECK | APPROVAL | 新華科· 新華科· 新華科· 新華科· 新華科· 新華科· 新華科· 新華科· |
| 吴佳斌 | 秋城場 | 主献点 | 技术部 |

Jiangsu HD-Crystal technology CO., Ltd

Add: NO 3, Dongxu Road, Lingang City, Jiangyin, Jiangsu Procince

Tel: +86 510 86680199 Fax: +86 510 86680699

Specification Revision Record Sheet

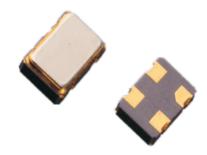
| Rev. | Revise page | Revise Contents | Date | Ref. No. | Reviser |
|------|-------------|------------------|-----------|----------|---------|
| A/0 | N/A | Initial released | 2018/3/30 | N/A | 吴佳斌 |
| A/1 | N/A | P/N revision | 2020/1/1 | N/A | 吴佳斌 |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |
| | | | | | |

Product Descipion

8Q148500301

1. Scope:

1.1 This specification applies to the RoHS crystal oscillator with a frequency of 148.500 MHz which will be used in electronic equipment.



2. Construction:

2.1 Oscillators series: QMEMS5032 8Q series

2.2 Package: SMD 5.0×3.2

3. Electrical Characteristics

| 3.1 | Nominal Frequency: | 148.500MHz |
|-----|----------------------|------------|
| 3.2 | Frequency Stability: | ±30ppm |

(incl. 25°C tolerance, tolerance over operating temperature range, input voltage change, load change, 1 year aging)

| 3.3 | Aging: | ±3ppm/year |
|------|-----------------------------------|----------------|
| 3.4 | Operating Temperature Range: | -40 to + 85°C |
| 3.5 | Storage Temperature Range: | -55 to + 125°C |
| 3.6 | Input Voltage (V _{DD}): | +3.3Vdc±10% |
| 3.7 | Input Current (I _{DD}): | 36mA max |
| 3.8 | Output Waveform: | CMOS |
| 3.9 | Output Symmetry: | 50±5% |
| 3.10 | Rise/Fall Time: | 5ns max |
| 3.11 | Output Voltage V _{OL} : | 10%VDD |
| | V _{OH} : | 90%VDD |
| | | |

3.12 Output Load: 15pF

3.13 Output State Control: Enable/disable

3.14 Start-up Time: 8ms max

3.15 Phase Jitter (rms): 1ps rms max 12kHz to 20MHz max

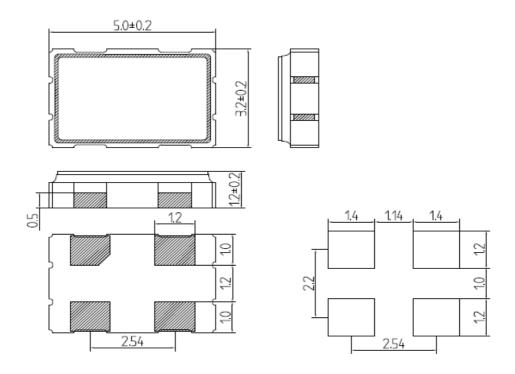
3.16 Oscillation mode: Fundmental

3.17 Others:Not recommended for safety applications

Reliability Specification

| NO. | ITEM | SPECIFICATION | TEST METHOD |
|------|---|--|--|
| 4.1 | Temperature Cycle (GB/T 2423.22-2002, Method Nb) | Frequency change after test≤± 5ppm. | 10 cycles from -55°C to 125°C. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.2 | Low Temperature Storage (GB/T 2423.1-2001, Method Aa) | Frequency change after test≤± 5ppm. | Spending 72 hrs at -55°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.3 | High Temperature Storage (GB/T 2423.2-2001, Method Ba) | Frequency change after test≤± 5ppm. | Spending 72 hrs at 125°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.4 | Humidity (GB/T 2423.3- 2006, Method Cab) | Frequency change after test≤± 5ppm. | Spending 96 hrs at 40 °C ± 3 °C, with 90± 3% R.H. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.5 | Vibration (GB/T 2423.10- 1995, Method Fc) | Frequency change after test≤± 5ppm. | Apply 0.75mm vibration at sweep frequency $10\sim500$ Hz, for 2h. 10 cycles in each direction of 3 axis. Measurement taken after 1 hour. |
| 4.6 | Shock (GB/T 2423.5-1995, Method Ea) | Frequency change after test≤± 5ppm. No visible damages. | Peak 1000m/s2, normal width 6ms half sine wave form, 3.7m/s, 3 perpendicular axis of samples, 3 cycles / direction, total 18 cycles. Measurement taken after 1 hour. |
| 4.7 | Drop (GB/T 2423.8-1995, Method Ed) | Frequency change after test≤± 5ppm. No visible damages. | Free drop to the wooden plate from 1.0 m heights for 3 times. |
| 4.8 | Solderability (GB/T 2423.28-2005, Method Tc) | Terminals shall be covered more then 95% with solder. | In 245 \pm 5°C solder bath for 2 \pm 0.5 seconds. There is no need to do functioned test. 8-12X magnifier. |
| 4.9 | Terminal Strength (JIS-C-6429 Method 1 & 2) | No visible damage | Mount on a glass-epoxy board (100x50x1.6mm), then bend to 2mm displacement (velocity 1mm/sec) and keep for 5 seconds. or pulling force 0.5 kg for at least 60 seconds. |
| 4.10 | Resistance to Soldering Heat (GB/T 2423.28-2005, Test Tb Method 1B) | Frequency change after test≤± 5ppm. | Passed through the re-flow oven under the following condition. Preheat to 150°C±5°C for 60 to 120sec,and peak 265°C±5°C for 10s±3sec.Measurement taken after DUT being left at room temperature for at 24±2 hours. |
| | | | |
| | | | |
| | | | |
| 4.11 | OTHERS | | |

Package Outline Dimensions



unit: mm

PIN CONNECTION

| P/N | Features |
|-----|-----------------|
| 1 | Enable/Disable* |
| 2 | GND |
| 3 | Output |
| 4 | VDD |

Packing Specification

